TrenchMV[™] Power MOSFET

IXTF230N085T

(Electrically Isolated Back Surface)

N-Channel Enhancement Mode Avalanche Rated

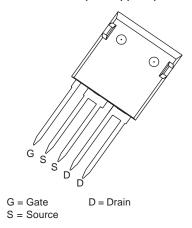


Symbol	Test Conditions	Maximum F	Maximum Ratings		
V _{DSS} V _{DGR}	$T_J = 25^{\circ}\text{C} \text{ to } 175^{\circ}\text{C}$ $T_J = 25^{\circ}\text{C to } 175^{\circ}\text{C}; R_{GS} = 1 \text{ M}\Omega$	85 55	V		
V _{GSM}	Transient	± 20	V		
 {D25} 	$T{\rm C} = 25^{\circ}{\rm C}$ Package Current Limit, RMS (75 A per lea $T_{\rm C} = 25^{\circ}{\rm C}$, pulse width limited by $T_{\rm IM}$	130 ad) 150 520	A A A		
I _{DM} I _{AR} E _{AS}	$T_{\rm c} = 25^{\circ}{\rm C}$ $T_{\rm c} = 25^{\circ}{\rm C}$ $T_{\rm c} = 25^{\circ}{\rm C}$	40 1.5	A		
dv/dt	$I_{s} \leq I_{DM}$, di/dt \leq 100 A/ms, $V_{DD} \leq V_{DSS}$ $T_{J} \leq$ 175°C, $R_{G} = 3.3 \Omega$	3	V/ns		
P _D	T _c = 25°C	200	W		
T _J T _{JM} T _{stg}		-55 +175 175 -55 +175	°C °C °C		
T _L T _{SOLD}	1.6 mm (0.062 in.) from case for 10 s Plastic body for 10 seconds	300 260	°C °C		
V _{ISOL}	50/60 Hz, t = 1 minute, I _{ISOL} < 1 mA, RMS 25	500 V			
F _c	Mounting force	20120/4.525	N/lb.		
Weight		6	g		

Symbol	Test Conditions	C	Characteristic Values		
$(T_J = 25^{\circ}C \text{ unless otherwise specified})$		Mir	. Typ.	Max.	
BV _{DSS}	$V_{GS} = 0 \text{ V}, I_{D} = 250 \text{ mA}$	85	1		V
V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \text{ mA}$	2.0)	4.0	V
I _{GSS}	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			± 200	nA
I _{DSS}	$V_{DS} = V_{DSS}$ $V_{GS} = 0 V$	T _J = 150°C		5 250	μ Α μ Α
R _{DS(on)}	$V_{GS} = 10 \text{ V}, I_{D} = 50 \text{ A}, \text{ Note}$	es 1, 2		5.3 ו	mΩ

 $V_{DSS} = 85 V$ $I_{D25} = 130 A$ $R_{DS(on)} \le 5.3 m\Omega$

ISOPLUS i4-Pak™ (5-lead) (IXTF)



Features

- Ultra-low On Resistance
- Unclamped Inductive Switching (UIS) rated
- Low package inductance
- easy to drive and to protect
- 175 °C Operating Temperature

Advantages

- Easy to mount
- Space savings
- High power density

Applications

- Automotive
 - Motor Drives
 - 42V Power Bus
 - ABS Systems
- DC/DC Converters and Off-line UPS
- Primary Switch for 24V and 48V Systems
- Distributed Power Architechtures and VRMs
- Electronic Valve Train Systems
- High Current Switching Applications
- High Voltage Synchronous Recifier

DS99746 (01/07)

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Symbol	Test Conditions $(T_J = 25)$		Characteristic Values unless otherwise specified)		
		Min.	Тур.	Max.	
\mathbf{g}_{fs}	$V_{DS} = 10 \text{ V}; I_{D} = 60 \text{ A}, \text{ Note 1}$	75	125	S	
C _{iss}			9900	pF	
C _{oss}	$V_{GS} = 0 \text{ V}, V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$		1230	pF	
C _{rss}			286	pF	
t _{d(on)}			32	ns	
t _r	$V_{GS} = 10 \text{ V}, V_{DS} = 0.5 \text{ V}_{DSS}, I_{D} = 50 \text{ A}$		49	ns	
t _{d(off)}	$R_{_{G}} = 3.3 \Omega $ (External)		56	ns	
t _f			39	ns	
Q _{g(on)}			187	nC	
\mathbf{Q}_{gs}	$V_{GS} = 10 \text{ V}, V_{DS} = 0.5 \text{ V}_{DSS}, I_{D} = 25 \text{ A}$		51	nC	
\mathbf{Q}_{gd}			55	nC	
R _{thJC}				0.75 °C/W	
R _{thCH}			0.15	°C/W	

Source-Drain Diode

Characteristic Values

T₁ = 25°C unless otherwise specified)

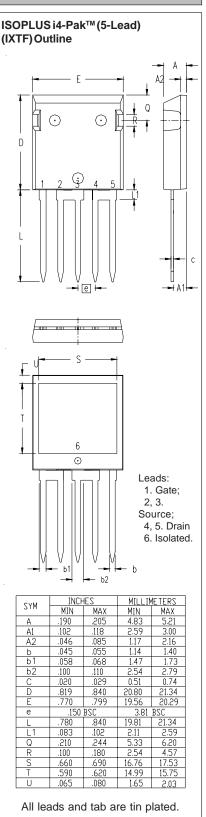
Symbol	Test Conditions	Min.	Тур.	Max.	
Is	$V_{GS} = 0 V$			150	Α
SM	Pulse width limited by $T_{_{JM}}$			520	Α
V _{SD}	$I_F = 50 \text{ A}, V_{GS} = 0 \text{ V}, \text{ Note 1}$			1.0	V
t _{rr}	$I_F = 25 \text{ A}, -di/dt = 100 \text{ A}/\mu\text{s}$		60		ns
	$V_{R} = 50 \text{ V}, V_{GS} = 0 \text{ V}$				

Notes: 1. Pulse test: $t \le 300 \,\mu\text{s}$, duty cycled $\le 2 \,\%$;

2. Drain and Source Kelvin contacts must be located less than 5 mm from the plastic body.

ADVANCETECHNICALINFORMATION

The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.



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IXYSMOSFETs and IGBTs are covered by 4,835,592 4,931,844 5,049,961 5,237,481